# Low frequency transistor (-20V, -5A) 2SB1386 / 2SB1412 / 2SB1326

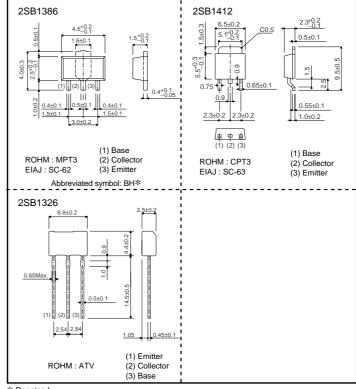
## Features

- 1) Low VCE(sat). VcE(sat) = -0.35V (Typ.)(Ic/IB = -4A/-0.1A)
- 2) Excellent DC current gain characteristics.
- 3) Complements the 2SD2098 / 2SD2118 / 2SD2097.

#### Structure

Epitaxial planar type PNP silicon transistor

## ●External dimensions (Unit : mm)



\* Denotes hre

## ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit		
Collector-base voltage		Vсво	-30	V		
Collector-emitter voltage		Vceo	-20	V		
Emitter-base voltage		VEBO	-6	V		
Collector current			-5	A(DC)		
		lc lc	-10	A(Pulse) *1		
Collector power dissipation	2SB1386		0.5	W		
			2	W *2		
	2SB1412	Pc	1	W		
		. 0	10	W(Tc=25°C)		
	2SB1326		1	W *3		
Junction temperature		Tj	150	°C		
Storage temperature		Tstg	-55 to 150	°C		

<sup>\*1</sup> Single pulse, Pw=10ms

# ●Electrical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	-30	_	_	V	Ic= -50μA	
Collector-emitter breakdown voltage		BVceo	-20	_	_	V	Ic=-1mA	
Emitter-base breakdown voltage		ВУЕВО	-6	_	_	V	Iε= -50μA	
Collector cutoff current		Ісво	_	_	-0.5	μΑ	Vcb= -20V	
Emitter cutoff current		ІЕВО	_	_	-0.5	μΑ	V <sub>EB</sub> = -5V	
Collector-emitter saturation voltage		VCE(sat)	_	0.35	-1.0	V	Ic/I <sub>B</sub> = -4A/ -0.1A *	
DC current transfer ratio	2SB1386,2SB1412	hfe	82	_	390	_	Vce= -2V. Ic= -0.5A	
	2SB1326		120	_	390	_	**	
Transition frequency		f⊤	_	120	_	MHz	Vc==-6V, I==50mA, f=100MHz	
Output capacitance		Cob	_	60	_	pF	Vсв= −20V, I∈=0A, f=1MHz	

 $<sup>\</sup>begin{tabular}{ll} * Measured using pulse current. \end{tabular}$ 

# ●Packaging specifications and hfe

		Package	Taping		
		Code	T100	TL	TV2
Туре	hfe	Basic ordering unit (pieces)	1000	2500	2500
2SB1386	PQR		0	-	_
2SB1412	PQR		-	0	_
2SB1326	QR		_	_	0

## hre values are classified as follows:

Item	Р	Q	R	
hfe	82 to 180	120 to 270	180 to 390	

<sup>\*2</sup> When mounted on a 40×40×0.7 mm ceramic board.

 $<sup>{\</sup>rm *3\ \ Printed\ circuit\ board\ glass\ epoxy\ board\ 1.6\ mm\ thick\ with\ copper\ plating\ 100mm^2\ or\ larger.}$ 

#### Electrical characteristic curves

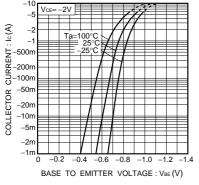


Fig.1 Grounded emitter propagation characteristics

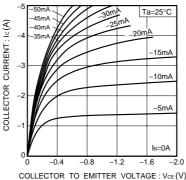


Fig.2 Grounded emitter output characteristics

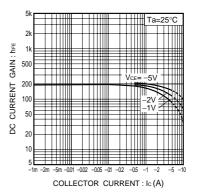


Fig.3 DC current gain vs. collector current ( I )

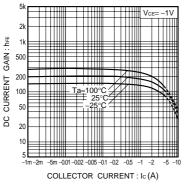


Fig.4 DC current gain vs. collector current (II)

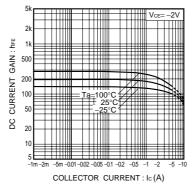


Fig.5 DC current gain vs. collector current (III)

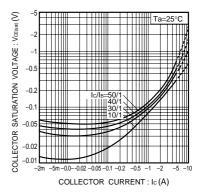


Fig.6 Collector-emitter saturation voltage vs. collector current ( I )

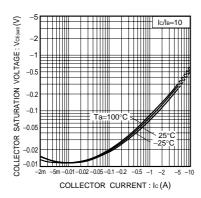


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

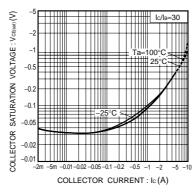


Fig.8 Collector-emitter saturation voltage vs. collector current (III)

ROHM

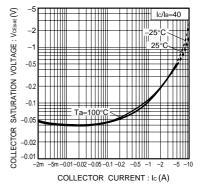
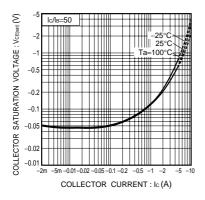
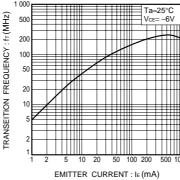


Fig.9 Collector-emitter saturation voltage vs. collector current (IV)





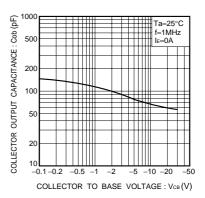


Fig.10 Collector-emitter saturation voltage vs. collector current (V)

Fig.11 Gain bandwidth product vs. emitter current

Fig.12 Collector output capacitance vs. collector-base voltage

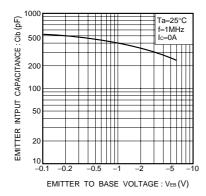


Fig.13 Emitter input capacitance vs. emitter-base voltage

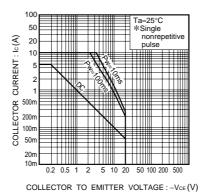


Fig.14 Safe operation area

(2SB1412)

## Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
  means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
  product described in this document are for reference only. Upon actual use, therefore, please request
  that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
  use and operation. Please pay careful attention to the peripheral conditions when designing circuits
  and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

### About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

